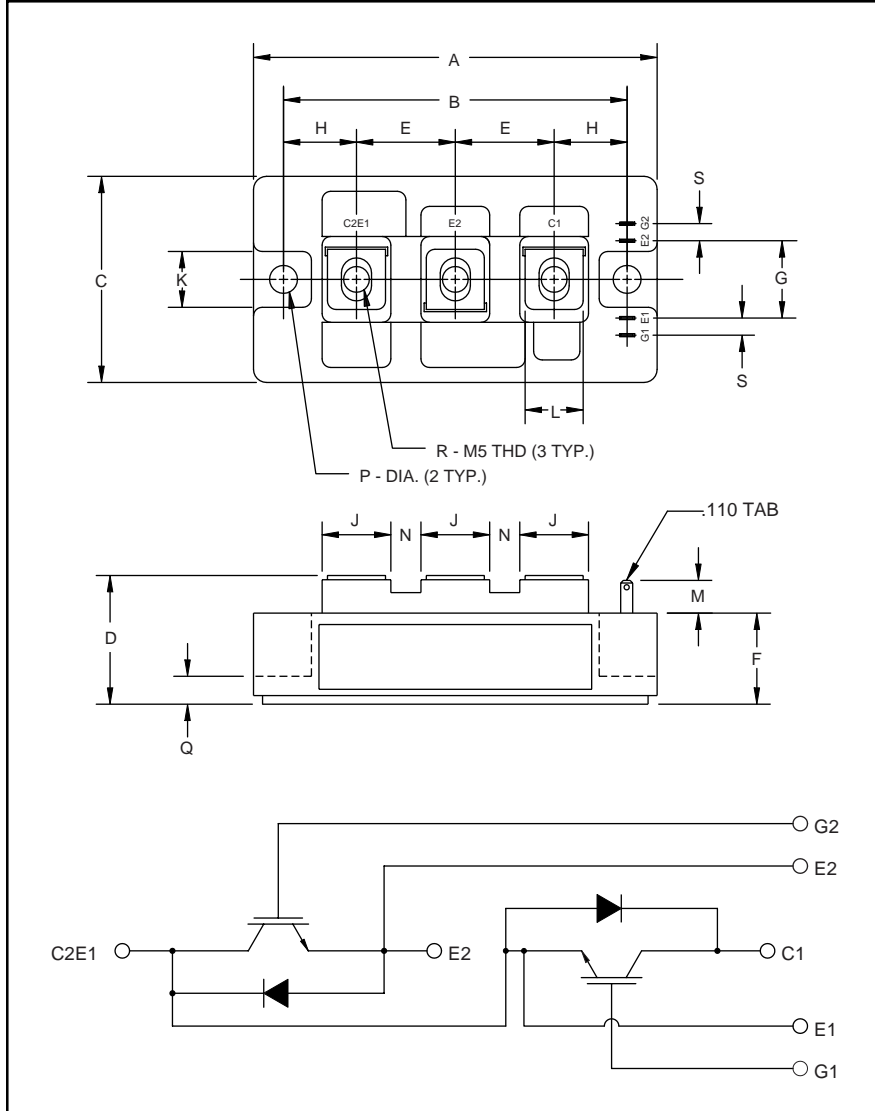


### Dual IGBTMOD™ H-Series Module 300 Amperes/600 Volts



Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	3.70	94.0
B	3.150±0.01	80.0±0.25
C	1.89	48.0
D	1.18 Max.	30.0 Max.
E	0.90	23.0
F	0.83	21.2
G	0.71	18.0
H	0.67	17.0
J	0.63	16.0

Dimensions	Inches	Millimeters
K	0.51	13.0
L	0.47	12.0
M	0.30	7.5
N	0.28	7.0
P	0.256 Dia.	Dia. 6.5
Q	0.26	6.5
R	M5 Metric	M5
S	0.16	4.0



#### Description:

Powerex IGBTMOD™ Modules are designed for use in switching applications. Each module consists of two IGBT Transistors in a half-bridge configuration with each transistor having a reverse-connected super-fast recovery free-wheel diode. All components and interconnects are isolated from the heat sinking baseplate, offering simplified system assembly and thermal management.

#### Features:

- Low Drive Power
- Low  $V_{CE(sat)}$
- Discrete Super-Fast Recovery (70ns) Free-Wheel Diode
- High Frequency Operation (20-25kHz)
- Isolated Baseplate for Easy Heat Sinking

#### Applications:

- AC Motor Control
- Motion/Servo Control
- UPS
- Welding Power Supplies
- Laser Power Supplies

#### Ordering Information:

Example: Select the complete part module number you desire from the table below -i.e. CM300DY-12H is a 600V ( $V_{CES}$ ), 300 Ampere Dual IGBTMOD™ Power Module.

Type	Current Rating Amperes	$V_{CES}$ Volts (x 50)
CM	300	12

**CM300DY-12H**  
**Dual IGBTMOD™ H-Series Module**  
 300 Amperes/600 Volts

**Absolute Maximum Ratings,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Ratings	Symbol	CM300DY-12H	Units
Junction Temperature	$T_j$	-40 to 150	$^\circ\text{C}$
Storage Temperature	$T_{\text{stg}}$	-40 to 125	$^\circ\text{C}$
Collector-Emitter Voltage (G-E SHORT)	$V_{\text{CES}}$	600	Volts
Gate-Emitter Voltage	$V_{\text{GES}}$	$\pm 20$	Volts
Collector Current	$I_C$	300	Amperes
Peak Collector Current	$I_{\text{CM}}$	600*	Amperes
Diode Forward Current	$I_F$	300	Amperes
Diode Forward Surge Current	$I_{\text{FM}}$	600*	Amperes
Power Dissipation	$P_d$	1100	Watts
Max. Mounting Torque M5 Terminal Screws	–	17	in-lb
Max. Mounting Torque M6 Mounting Screws	–	26	in-lb
Module Weight (Typical)	–	270	Grams
V Isolation	$V_{\text{RMS}}$	2500	Volts

\* Pulse width and repetition rate should be such that device junction temperature does not exceed the device rating.

**Static Electrical Characteristics,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Cutoff Current	$I_{\text{CES}}$	$V_{\text{CE}} = V_{\text{CES}}, V_{\text{GE}} = 0\text{V}$	–	–	1.0	mA
Gate Leakage Current	$I_{\text{GES}}$	$V_{\text{GE}} = V_{\text{GES}}, V_{\text{CE}} = 0\text{V}$	–	–	0.5	$\mu\text{A}$
Gate-Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$I_C = 30\text{mA}, V_{\text{CE}} = 10\text{V}$	4.5	6.0	7.5	Volts
Collector-Emitter Saturation Voltage	$V_{\text{CE(sat)}}$	$I_C = 300\text{A}, V_{\text{GE}} = 15\text{V}$	–	2.1	2.8**	Volts
		$I_C = 300\text{A}, V_{\text{GE}} = 15\text{V}, T_j = 150\text{ }^\circ\text{C}$	–	2.15	–	Volts
Total Gate Charge	$Q_G$	$V_{\text{CC}} = 300\text{V}, I_C = 300\text{A}, V_{\text{GS}} = 15\text{V}$	–	900	–	nC
Diode Forward Voltage	$V_{\text{FM}}$	$I_E = 300\text{A}, V_{\text{GS}} = 0\text{V}$	–	–	2.8	Volts

\*\* Pulse width and repetition rate should be such that device junction temperature rise is negligible.

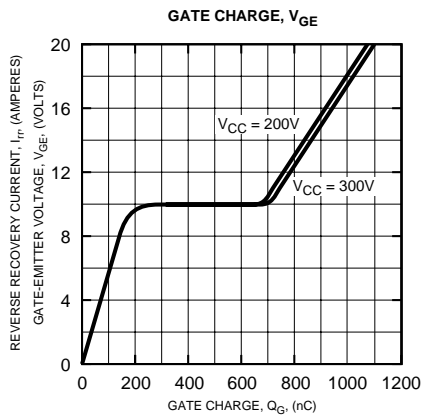
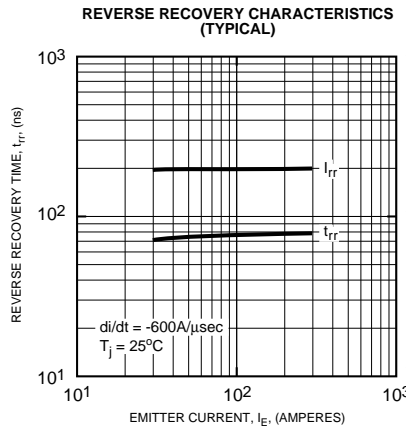
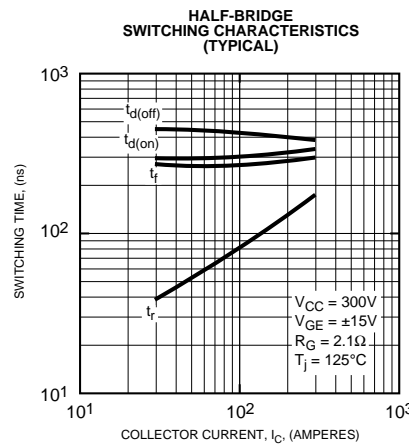
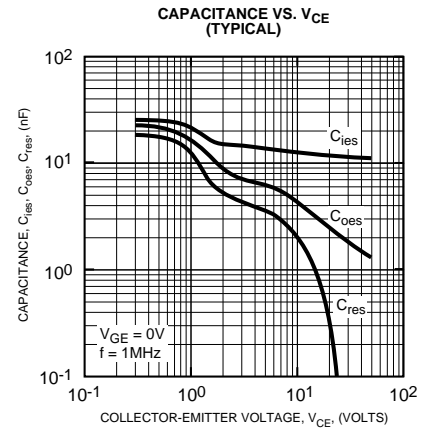
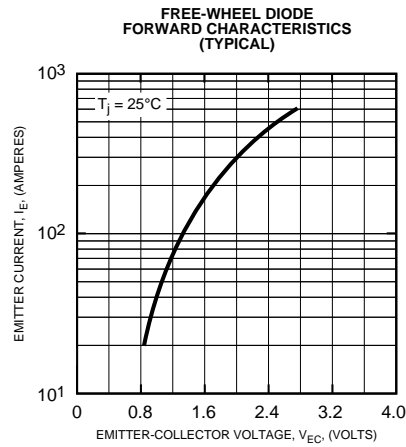
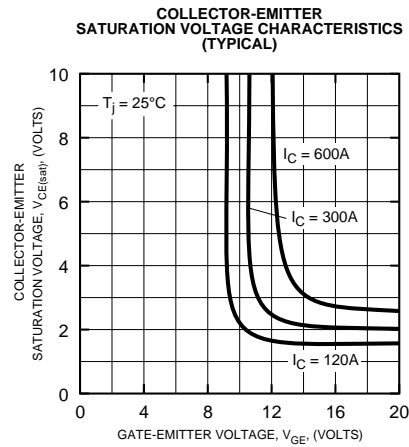
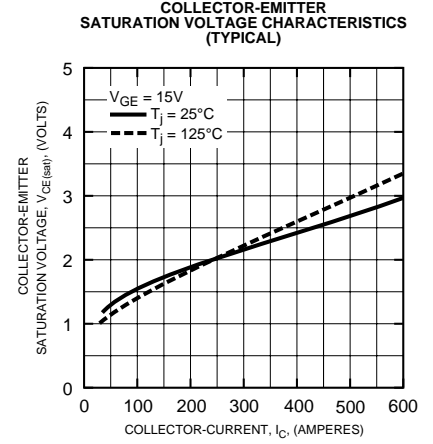
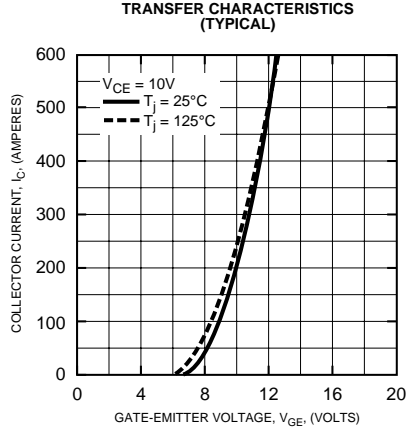
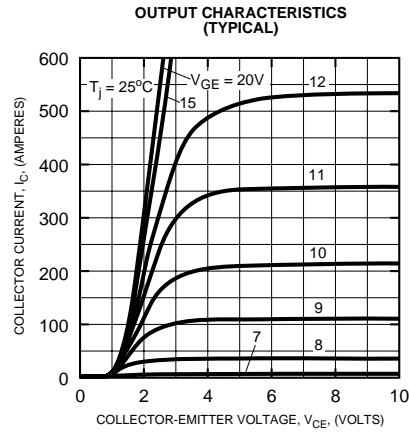
**Dynamic Electrical Characteristics,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units	
Input Capacitance	$C_{\text{ies}}$		–	–	30	nF	
Output Capacitance	$C_{\text{Oes}}$	$V_{\text{GE}} = 0\text{V}, V_{\text{CE}} = 10\text{V}, f = 1\text{MHz}$	–	–	10.5	nF	
Reverse Transfer Capacitance	$C_{\text{res}}$		–	–	6	nF	
Resistive	Turn-on Delay Time	$V_{\text{CC}} = 300\text{V}, I_C = 300\text{A},$ $V_{\text{GE1}} = V_{\text{GE2}} = 15\text{V}, R_G = 2.1\Omega$	–	–	350	ns	
Load	Rise Time						$t_{\text{d(on)}}$
Switching	Turn-off Delay Time						$t_r$
Times	Fall Time		–	–	300	ns	
Diode Reverse Recovery Time	$t_{\text{rr}}$	$I_E = 300\text{A}, di_E/dt = -600\text{A}/\mu\text{s}$	–	–	110	ns	
Diode Reverse Recovery Charge	$Q_{\text{rr}}$	$I_E = 300\text{A}, di_E/dt = -600\text{A}/\mu\text{s}$	–	0.81	–	$\mu\text{C}$	

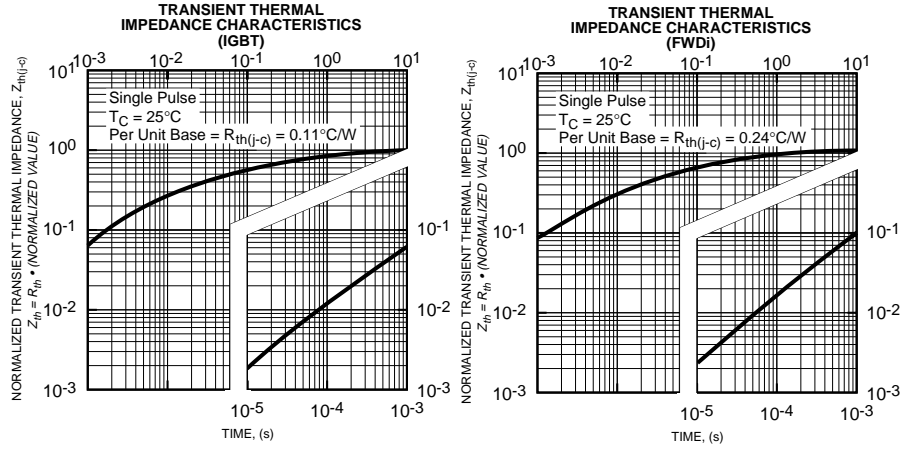
**Thermal and Mechanical Characteristics,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction to Case	$R_{\text{th(j-c)}}$	Per IGBT	–	–	0.11	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\text{th(j-c)}}$	Per FWDi	–	–	0.24	$^\circ\text{C}/\text{W}$
Contact Thermal Resistance	$R_{\text{th(c-f)}}$	Per Module, Thermal Grease Applied	–	–	0.065	$^\circ\text{C}/\text{W}$

**CM300DY-12H**  
**Dual IGBTMOD™ H-Series Module**  
 300 Amperes/600 Volts



**CM300DY-12H**  
**Dual IGBTMOD™ H-Series Module**  
 300 Amperes/600 Volts



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